	OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS SGDS017 - FEBRUARY 2002
 Q Devices Meet Automotive Performa Requirements 	nce DW OR PW PACKAGE (TOP VIEW)
 Customer-Specific Configuration Con Can Be Supported Along With Major-Change Approval 	trol 10E 1 201 V _{CC} 1A1 2 19 20E 2Y4 3 18 1Y1
 EPIC[™] (Enhanced-Performance Impla CMOS) Process 	nted 1A2 [4 17] 2A4 2Y3 [5 16] 1Y2
 Operating Range 2-V to 5.5-V V_{CC} 	1A3 🚺 6 15 🗍 2A3
• Latch-Up Performance Exceeds 250 m	1A Per 2Y2 [7 14] 1Y3
JESD 17	1A4 <mark>[]</mark> 8 13 [] 2A2
	2Y1 [] 9 12 [] 1Y4
description	GND [10 11] 2A1

This octal buffer/driver is designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The SN74AHC244Q is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

T _A	PACKA	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC – D	Tape and reel	SN74AHC244QDWR	AHC244Q
-40 C 10 125 C	TSSOP – PW	Tape and reel	SN74AHC244QPWR	HA244Q

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE
(each 4-bit buffer/driver)

INPU	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
Н	Х	Z



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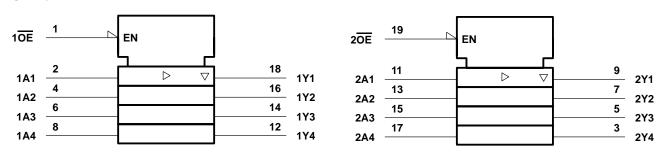
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SN74AHC244Q

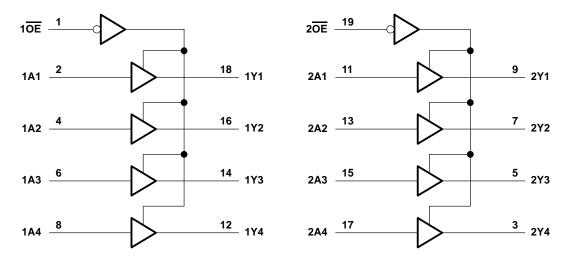
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V_{CC} Input voltage range, V_I (see Note 1) Output voltage range, V_O (see Note 1) Input clamp current, I_{IK} ($V_I < 0$) Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) Continuous output current, I_O ($V_O = 0$ to V_{CC})	$\begin{array}{ccc} -0.5 \ V \ to \ 7 \ V \\ \dots -0.5 \ V \ to \ V_{CC} + 0.5 \ V \\ \dots & -20 \ \text{mA} \\ \dots & \pm 20 \ \text{mA} \end{array}$
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	58°C/W
PW package	83°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	V
		$V_{CC} = 2 V$	1.5		
VIH	High-level input voltage	$V_{CC} = 3 V$	2.1		V
		V _{CC} = 5.5 V	3.85		
		$V_{CC} = 2 V$		0.5	
VIL	Low-level input voltage V _{CC} = 3 V			0.9	V
		V _{CC} = 5.5 V		1.65	
٧I	Input voltage		0	5.5	V
٧ ₀	Output voltage		0	VCC	V
		$V_{CC} = 2 V$		-50	μΑ
IОН	High-level output current	V_{CC} = 3.3 V ± 0.3 V		-4	mA
		V_{CC} = 5 V ± 0.5 V		-8	ША
		$V_{CC} = 2 V$		50	μΑ
IOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	~ ^
		$V_{CC} = 5 V \pm 0.5 V$		8	mA
A+/A.		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	ns/V
$\Delta t / \Delta v$	Input transition rise or fall rate $V_{CC} = 5 V \pm V_{CC}$			20	115/ V
Т _А	Operating free-air temperature		-40	125	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vee	T _A = 25°C			MIN	МАХ	UNIT
FARAINETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	WIIN	WAA	UNIT
VOH		2 V	1.9	2		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		
		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1	V
VOL		4.5 V			0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5	
	I _{OL} = 8 mA	4.5 V			0.36		0.5	
lj	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μA
I _{OZ}	$V_{O} = V_{CC} \text{ or GND}, V_{I} (\overline{OE}) = V_{IL} \text{ or } V_{IH}$	5.5 V			±0.25		±2.5	μA
ICC	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			4		40	μA
Ci	$V_I = V_{CC}$ or GND	5 V		2	10			pF
Co	$V_{O} = V_{CC}$ or GND	5 V		3.5				pF



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	TO LOAD		λ = 25°C	;	MIN	МАХ	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNIT
^t PLH	А	Y	C _I = 15 pF		5.8	8.4	1	10	ns
^t PHL		T	CL= 15 pr		5.8	8.4	1	10	115
^t PZH	OE	Y	C _L = 15 pF		6.6	10.6	1	12.5	ns
^t PZL		Y	$C_L = 15 \text{ pr}$		6.6	10.6	1	12.5	115
^t PHZ		Y	C _L = 15 pF		5	9.7	1	11	ns
^t PLZ	UE		CL = 15 pr		5	9.7	1	11	115
^t PLH	А	Y	C ₁ = 50 pF		8.3	11.9	1	13.5	ns
^t PHL			0L = 30 pr		8.3	11.9	1	13.5	115
^t PZH	OE	Y	C ₁ = 50 pF		9.1	14.1	1	16	ns
^t PZL			0L = 50 pF		9.1	14.1	1	16	115
^t PHZ	OE	Y	C _L = 50 pF		10.3	14	1	16	200
^t PLZ		T	CL = 50 PF		10.3	14	1	16	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Т	₄ = 25°C	;	MIN	МАХ	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE MIN TYP MAX		IVIAA	UNIT			
^t PLH	А	Y	C _I = 15 pF		3.9	5.5	1	6.5	ns
t _{PHL}	~	Ι	CL = 15 pr		3.9	5.5	1	6.5	115
^t PZH	ŌĒ	Y	Ci = 15 pF		4.7	7.3	1	8.5	ns
^t PZL	OE	Ι	C _L = 15 pF		4.7	7.3	1	8.5	115
^t PHZ	OE	Y	Ci - 15 pE		5	7.2	1	8.5	ns
^t PLZ	ÛE	T	C _L = 15 pF		5	7.2	1	8.5	115
^t PLH	А	Y	$C_{1} = 50 \text{ pc}$		5.4	7.5	1	8.5	
^t PHL	A	T	C _L = 50 pF		5.4	7.5	1	8.5	ns
^t PZH		Y	$C_{1} = 50 \text{ pF}$		6.2	9.3	1	10.5	50
^t PZL	OE	T	C _L = 50 pF		6.2	9.3	1	10.5	ns
^t PHZ	ŌĒ	Y	$C_{\rm L} = 50 \rm pF$		6.7	9.2	1	10.5	20
^t PLZ	UE	ſ	C _L = 50 pF		6.7	9.2	1	10.5	ns

noise characteristics, $V_{CC} = 5 V$, $C_L = 50 pF$, $T_A = 25^{\circ}C$ (see Note 4)

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5		V
VOL(V)	Quiet output, minimum dynamic V _{OL}		-0.2		V
VOH(V)	Quiet output, minimum dynamic V _{OH}		4.8		V
VIH(D)	High-level dynamic input voltage	3.5			V
V _{IL(D)}	Low-level dynamic input voltage			1.5	V

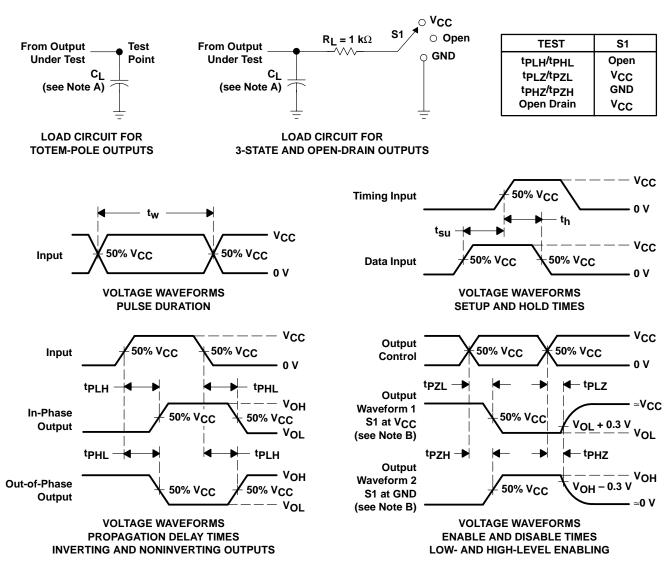
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1 MHz	8.6	pF



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C₁ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





17-Mar-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC244QDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		AHC244Q	Samples
SN74AHC244QDWRG4Q1	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		AHC244Q1	Samples
SN74AHC244QPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244Q	Samples
SN74AHC244QPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		HA244Q	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC244QDWRG4	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC244QDWRG4Q 1	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

20-Dec-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC244QDWRG4	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC244QDWRG4Q1	SOIC	DW	20	2000	367.0	367.0	45.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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